GU1M-E

SURFACE MOUNT SWITCHING RECTIFIER

VOLTAGE: 1000V

CURRENT: 1.0A

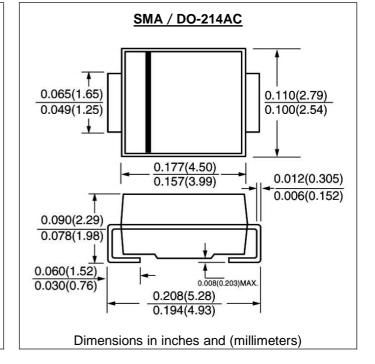




Ideal for surface mount pick and place application Low profile package Built-in strain relief High surge capability High temperature soldering guaranteed 260 °C/10sec/at terminals Glass passivated chip Fast recovery time for high efficiency Halogen Free

MECHANICAL DATA

Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C Case : Molded with UL-94 class V-0 recognized Halogen Free Epoxy Polarity: color band denotes cathode



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

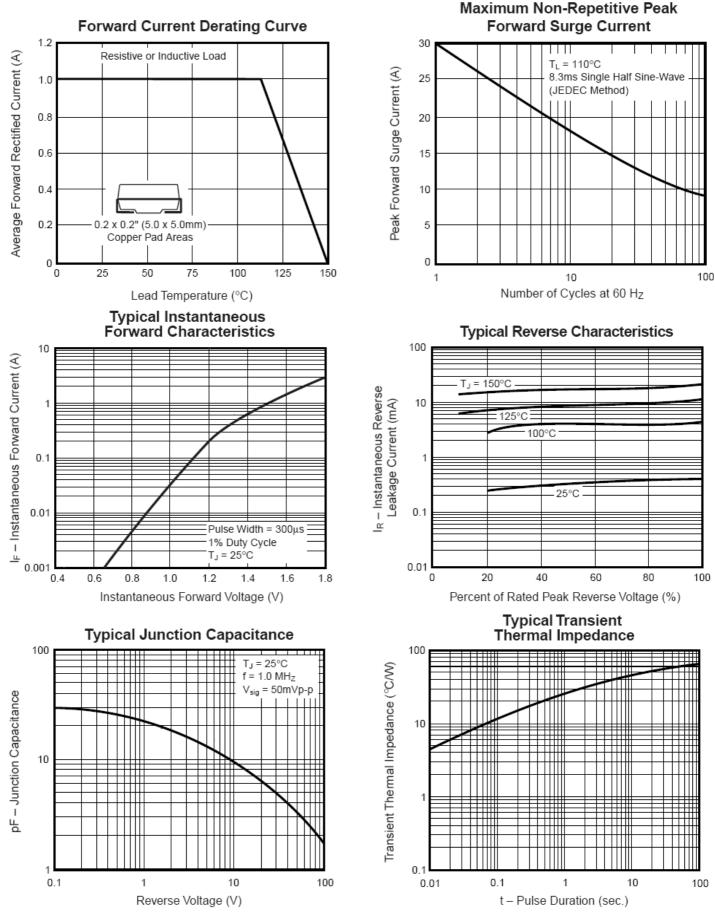
	SYMBOL	GU1M-E	units
Maximum Recurrent Peak Reverse Voltage	Vrrm	1000	V
Maximum RMS Voltage	Vrms	700	V
Maximum DC blocking Voltage	Vdc	1000	V
Maximum Average Forward Rectified Current 3/8"lead length at T_L =110 $^\circ\!\mathrm{C}$	lf(av)	1.0	A
Peak Forward Surge Current 8.3ms single half sine- wave superimposed on rated load	lfsm	30.0	A
Maximum Forward Voltage at rated forward current	Vf	1.7	V
Maximum DC Reverse CurrentTa = 25° Cat rated DC blocking voltageTa = 100° C	lr	10.0 500.0	μA
Maximum Reverse Recovery Time (Note1)	Trr	75	nS
Typical Junction Capacitance (Note 2)	Cj	15.0	pF
Typical Thermal Resistance (Note 3)	Rth(jl)	30.0	°C/W
Storage and Operating Junction Temperature	Tstg, Tj	-50 to +150	°C

Note:

1. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A

2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc

3. Thermal Resistance from Junction to terminal mounted on 5x5mm copper pad area



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RATINGS AND CHARACTERISTIC CURVES GU1M-E

Rev.A1